

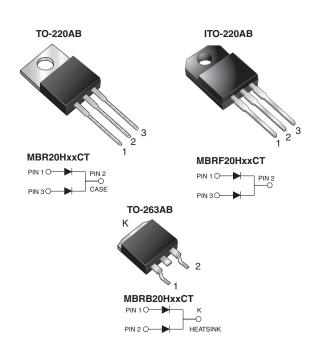
MBR(F,B)20H35CT thru MBR(F,B)20H60CT

Vishay General Semiconductor

RoHS

Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A x 2				
V_{RRM}	35 V to 60 V				
I _{FSM}	150 A				
V_{F}	0.55 V, 0.61 V				
I _R	100 μΑ				
T _J max.	175 °C				

FEATURES

- Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	MBR20H35CT	MBR20H45CT	MBR20H50CT	MBR20H60CT	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50 60				
Working peak reverse voltage	V_{RWM}	35	45	50 60		V		
Maximum DC blocking voltage	V_{DC}	35	45	50	60			
Maximum average forward rectified total device	I=		2	0		Α		
current (Fig.1) per diode	I _{F(AV)}		1	0		A		
Non-repetitive avalanche energy per diode at 25 $^{\circ}$ C, I _{AS} = 4 A, L = 10 mH	E _{AS}	80						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150						
Peak repetitive reverse surge current per diode at $t_p = 2.0 \mu s$, 1 kHz	I _{RRM}	1.0 0.5			А			
Peak non-repetitive reverse energy (8/20 µs waveform)	E _{RSM}	20 10			mJ			
Electrostatic discharge capacitor voltage Human body model: $C=100~pF,~R=1.5~k\Omega$	V _C	25						
Voltage rate of change (rated V _R)	dV/dt	10 000						
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to 175				°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V_{AC}	1500			٧			



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBR20H35CT MBR20H45CT		MBR20H50CT MBR20H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	-	0.63	-	0.71	- V
		I _F = 10 A	T _C = 125 °C	0.49	0.55	0.57	0.61	
		I _F = 20 A	T _C = 25 °C	-	0.75	-	0.85	
		I _F = 20 A	T _C = 125 °C	0.62	0.68	0.68	0.71	
Maximum reverse current per diode	I _R ⁽²⁾	I _R ⁽²⁾ Rated V _R	T _J = 25 °C	-	100	-	100	μΑ
			T _J = 125 °C	4.0	12	2.0	12	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical resistance, junction to case per diode	$R_{ heta JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR20H45CT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	MBRF20H45CT-E3/45	1.99	45	50/tube	Tube			
TO-263AB	MBRB20H45CT-E3/45	1.35	45	50/tube	Tube			
TO-263AB	MBRB20H45CT-E3/81	1.35	81	800/reel	Tape and reel			
TO-220AB	MBR20H45CTHE3/45 (1)	1.85	45	50/tube	Tube			
ITO-220AB	MBRF20H45CTHE3/45 ¹⁾	1.99	45	50/tube	Tube			
TO-263AB	MBRB20H45CTHE3/45 (1)	1.35	45	50/tube	Tube			
TO-263AB	MBRB20H45CTHE3/81 (1)	1.35	81	800/reel	Tape and reel			

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

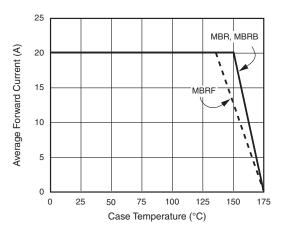


Fig. 1 - Forward Current Derating Curve (Total)

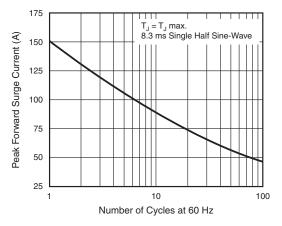


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

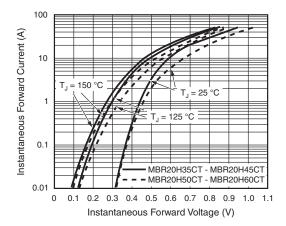


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

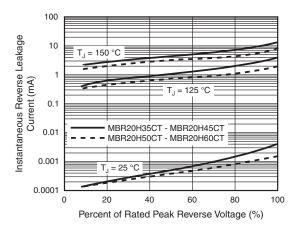


Fig. 4 - Typical Reverse Characteristics Per Diode

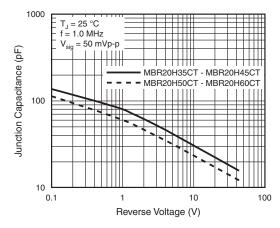


Fig. 5 - Typical Junction Capacitance Per Diode

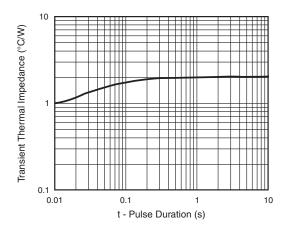


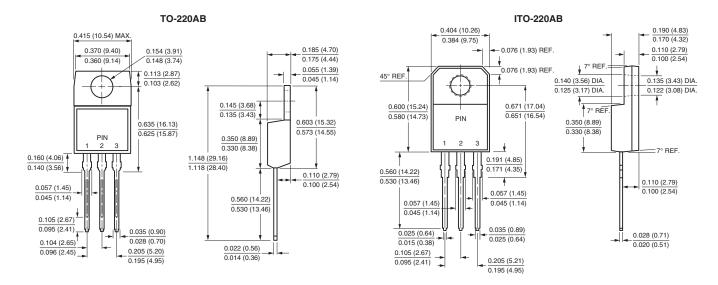
Fig. 6 - Typical Transient Thermal Impedance Per Diode



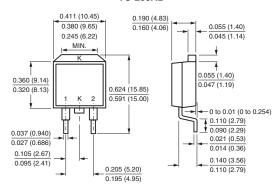
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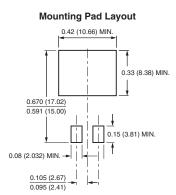
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB







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